63rd ANNUAL CONFERENCE OF THE SA INSTITUTE OF PHYSICS



Contribution ID: 18

Type: Oral Presentation

Effect of substrate temperature on photoluminescence properties of Eu³⁺doped BaZrO₃ thin films deposited by PLD

Thursday, 28 June 2018 11:20 (20 minutes)

Perovskite type (A²⁺B⁴⁺O²⁻₃) structures are significantly important host for rare earth (RE) doping because they offer promising luminescence properties for light emitting diode, field emission display and all solid compact laser devices. Eu(³⁺ doped BaZrO₃ thin films with cubic structure were prepared on Si(100) substrates by using the pulse laser deposition (PLD) technique, using an Eu³⁺ doped BaZrO₃ target at 10 mTorr oxygen pressure. The substrate temperature was varied from 400°C to 700°C. The thicknesses of the films were calculated from transmittance spectra. The thickness of all the films were around 300 nm. The phase identification and structural properties of the films were characterized by X-ray diffractometry. Surface morphology were studied by Scanning Electron Microscopy. Elemental analysis was performed using X-ray photoelectron spectroscopy (XPS). The oxidation states were also confirmed from XPS analysis. With the increase in substrate temperature, the growth of the films changed. Intense red emission was observed by the excitation of UV light. Emission spectra showed peaks at 577, 597 and 615 nm corresponding to the $< \sup >5 </ \sup >D < \sup >0 </ \sup > \rightarrow <\sup >7 </ \sup >F < \sup >0 </ \sup >, <\sup >5 </ \sup >D <\sup >0 </ \sup > \rightarrow <\sup >7 </\sup >F <\sup >1 </ \sup >$ and ⁵D₀ \rightarrow ⁷F₂ transitions of Eu³⁺, respectively. tively. It was observed that the emission at 597 nm which was due to the magnetic dipole transition (⁵D_O-->sup was the dominating emission. This confirms that Eu3+ ion occupied the centro-symmetric Zr(⁴⁺ site. Emission properties and defects involved within the films were investigated via photoluminescence.

Keywords: PLD, Thin film, Photoluminescence

Please confirm that you
br>have carefully read the
br>abstract submission instructions
br>under the menu item
br>"Call for Abstracts"
br><b/(Yes / No)

Yes

N/A

Supervisor details

str>

student astudent, type N/A.

student abstract submision

supervisor permission:

br>please give their name,

institution and email address.

Prof. H.C.Swart, Department of Physics, University of Free State, P.O. Box 339, Bloemfontein, ZA 9300, South Africa.

Primary authors: Dr KUNTI, ARUP (University of the Free State); Prof. SWART, Hendrick (University of the

Free State); Prof. HÖLSÄ, Jorma (University of Turku)

Presenter: Dr KUNTI, ARUP (University of the Free State)

Session Classification: Physics of Condensed Matter and Materials

Track Classification: Track A - Physics of Condensed Matter and Materials